



UiO : **Department of Physics**
University of Oslo

Inelastic form factors, scattering cross sections, dipole selection rules

FYS5310/FYS9320

Lecture 4

16.02.2016



FYS5310 teaching schedule

Preliminary schedule only! You should keep the class-times on Wednesdays and Thursdays open unless notified by email (or in this schedule) that there is no class

References to the textbook to Fultz & Howe unless stated otherwise.

Date	Time	Lecture/lab	Topic	Chapters	Homework	
Wednesday	18.01.2017	14:15-16:00	Lecture	Introduction to the course. Derivation of the structure factor (01)	4.1, 4.3.1, 6.1	Exercise set 1 (handout)
Thursday	19.01.2017	12:15-14:00	Lecture	No class (SMN seminar)		
Wednesday	25.01.2017	13:15-16:00	Lab/Colloquium	Going through exercise set 1 + Lecture: The atomic form factor (02)	4.3	Excercise set 2 (handout)
Thursday	26.01.2017	12:15-14:00	Lecture	No class		
Wednesday	01.02.2017	14:15-16:00	Lab/colloquium	Going though exercise set 2		
Thursday	02.02.2017	12:15-14:00	Lecture	Uses of EELS and EELS instrumentation (03)	5.1, 5.2; W&C 37	Exercise set 3 (handout)
Wednesday	08.02.2017	14:15-16:00	Lab/colloquium	Going though exercise set 3		
Thursday	09.02.2017	12:15-14:00	Lecture	Inelastic form factors (04)	5.4.1-5.4.3 + primer on Dirac notation	
Wednesday	15.02.2017	12:15-16:00	Lab/colloquium	No class		
Thursday	16.02.2017	12:15-14:00	Lecture	Inelastic form factors, scattering cross sections, dipole selection rules (05)	5.4.4-5.4.7, W&C 39, plus Brehm and Mullin on parity and dipole selection rules	
Wednesday	22.02.2017	12:15-16:00	Lab/colloquium	No class		
Thursday	23.02.2017	12:15-14:00	Lecture	Core losses: Quantification and electronic structure (06)	5.4, W&C 39+40	Exercise set 4 (handout)
Wednesday	01.03.2017	12:15-16:00	Lab/colloquium	Going through excercise set 4		
Thursday	02.03.2017	12:15-14:00	Lecture	Low energy loss; electronic structure and dielectric properties pt 1 (07)		
Wednesday	08.03.2017	12:15-16:00	Lab/colloquium	Computer lab?		
Thursday	09.03.2017	12:15-14:00	Lecture	Low energy loss; electronic structure and dielectric properties pt 2 (08)	5.3, W&C 38	
Wednesday	15.03.2017	12:15-16:00	Lab/colloquium	No class		
Thursday	16.03.2017	12:15-14:00	Lecture	No class		
Wednesday	22.03.2017	12:15-16:00	Lab/colloquium	Computer lab?		

This lecture

- Recap from last time
 - The inelastic form factor
- Cross section of a single scattering event
- Cross section for several possible final states
- GOS
- Dipole selection rules

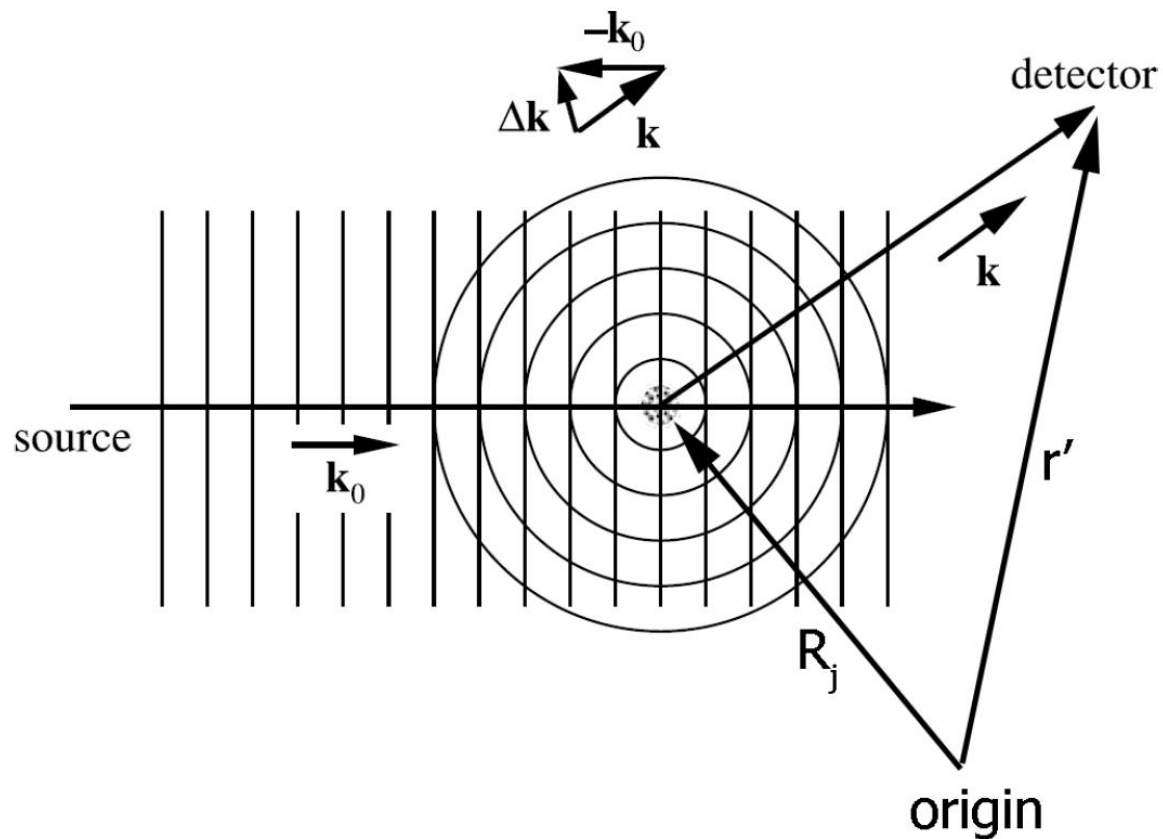


Figure 1: Sketch showing a plane wave scattered by atom in \mathbf{R}_j .

$$\begin{aligned} f(\mathbf{k}, \mathbf{k}_0) &= \frac{-m_e}{2\pi\hbar^2} \langle \beta | \langle \mathbf{k} | \frac{e^2}{|\mathbf{r}_1 - \mathbf{r}_2|} + V(\mathbf{r}_1) | \mathbf{k}_0 \rangle | \alpha \rangle \\ &= \frac{-m_e}{2\pi\hbar^2} \left[\langle \beta | \langle \mathbf{k} | \frac{e^2}{|\mathbf{r}_1 - \mathbf{r}_2|} | \mathbf{k}_0 \rangle | \alpha \rangle + \langle \beta | \langle \mathbf{k} | V(\mathbf{r}_1) | \mathbf{k}_0 \rangle | \alpha \rangle \right] \\ &= \frac{-m_e}{2\pi\hbar^2} \left[\langle \beta | \langle \mathbf{k} | \frac{e^2}{|\mathbf{r}_1 - \mathbf{r}_2|} | \mathbf{k}_0 \rangle | \alpha \rangle + \langle \beta | \alpha \rangle \langle \mathbf{k} | V(\mathbf{r}_1) | \mathbf{k}_0 \rangle \right] \\ &= \frac{-m_e}{2\pi\hbar^2} \left[\langle \beta | \langle \mathbf{k} | \frac{e^2}{|\mathbf{r}_1 - \mathbf{r}_2|} | \mathbf{k}_0 \rangle | \alpha \rangle \right] \end{aligned}$$

Fermi golden rule – scattering between two distinct states

$$\frac{d\sigma(\Delta\mathbf{k})}{d\Omega} = |f(\mathbf{k}, \mathbf{k}_0)|^2 = \frac{4}{a_0^2 \Delta k^4} \left| \int_{-\infty}^{\infty} \Psi_{\beta}^*(\mathbf{r}_2) e^{-i\Delta\mathbf{k}\cdot\mathbf{r}_2} \Psi_{\alpha}(\mathbf{r}_2) d^3\mathbf{r}_2 \right|^2$$

$\Delta\mathbf{k}$ – scattering vector $\Delta\mathbf{k} = \mathbf{k}_0 - \mathbf{k}$

Ψ_{α} – initial state of target electron

Ψ_{β} – final state of target electron

\mathbf{r}_2 – position of scattering event

Assumption 1

Only one scattering event at a time

Assumption 2

Separation of the electronic and atomic degrees of freedom

Double differential cross section

$\frac{d\sigma}{\Delta\mathbf{k}} \rightarrow \frac{d^2\sigma(\Delta\mathbf{k}, E)}{\Delta\mathbf{k}dE}$ We want to consider all possible transitions from Ψ_α with energy E

$$|\langle \beta | e^{-i\Delta\mathbf{k}\cdot\mathbf{r}} | \alpha \rangle|^2$$

Several possible final states with same energy

$$\frac{d^2\sigma(\Delta\mathbf{k}, E)}{d\Omega dE} = \frac{4}{a_0^2 \Delta k^4} \rho(E) |\langle \beta | e^{-i\Delta\mathbf{k}\cdot\mathbf{r}} | \alpha \rangle|^2$$

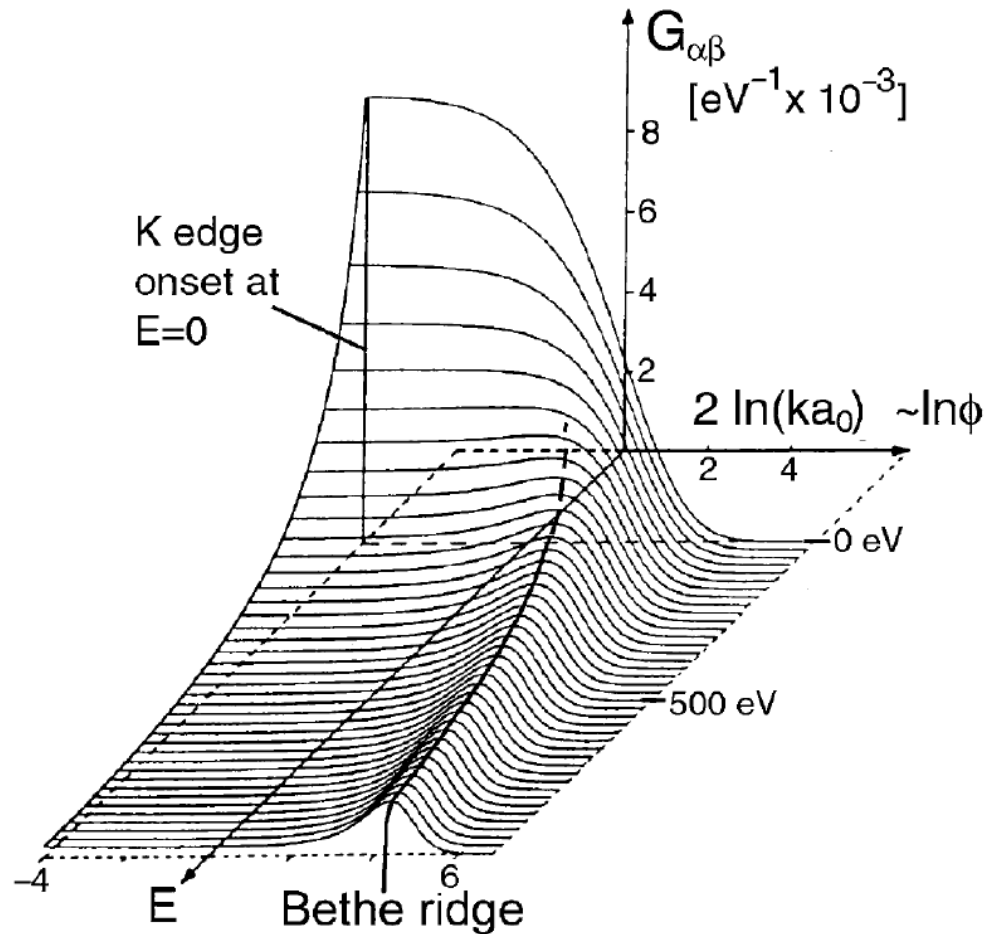
Assumption 3

Matrix element is a constant for all β under consideration

$$G_{\alpha\beta}(\Delta k, E) = E_{\alpha\beta} \frac{2m_e}{\hbar^2 \Delta k^2} \left| \int_{-\infty}^{\infty} \Psi_{\beta}^*(\mathbf{r}) e^{-i\Delta\mathbf{k}\cdot\mathbf{r}_2} \Psi_{\alpha}(\mathbf{r}_2) d^3\mathbf{r} \right|^2$$

$$\frac{d^2\sigma(\phi, E)}{d\phi dE} = \frac{2\pi\hbar^4}{a_0^2 m_2^2 E_{\alpha\beta} T} \underbrace{\frac{\phi}{\phi^2 + \phi_E^2}}_{\text{exp. scatt. angles}} \underbrace{\rho(E)}_{\text{sol. state eff.}} \underbrace{G_{\alpha\beta}(\Delta k, E)}_{\text{atomic osci. str.}}$$

Bethe surface for K -shell ionization of C, calculated using a hydrogenic model. The GOS is zero for energy losses below the ionization threshold $E_K = E_{\alpha\beta}$, or $E < 0$. The horizontal coordinate increases with scattering angle. The Bethe ridge is most distinct at large E towards the front of the figure. After [5.5]



Small scattering angles – the dipole selection rule

Most of the scattering is at small angles

Can be further limited by selecting small β

$$\Delta\mathbf{k} \cdot \mathbf{r} \ll 1 \quad e^x = 1 + x + \frac{x^2}{2!} + \frac{x^3}{3!} + \dots$$

$$e^{i\mathbf{q} \cdot \mathbf{r}} = 1 + i\Delta\mathbf{k} \cdot \mathbf{r} + \frac{(i\Delta\mathbf{k} \cdot \mathbf{r})^2}{2!} + \frac{(i\Delta\mathbf{k} \cdot \mathbf{r})^3}{3!} + \dots \quad \frac{d\sigma}{d\Delta\mathbf{k}} = \frac{4}{a_0\Delta\mathbf{k}^4} \left| \langle \beta | e^{i\Delta\mathbf{k} \cdot \mathbf{r}} | \alpha \rangle \right|^2$$

$$\frac{d\sigma}{d\Delta\mathbf{k}} \approx \frac{4}{a_0\Delta\mathbf{k}^4} \left| \langle \beta | 1 + i\Delta\mathbf{k} \cdot \mathbf{r} | \alpha \rangle \right|^2 = \frac{4}{a_0\Delta\mathbf{k}^4} \underbrace{\left| \langle \beta | i\Delta\mathbf{k} \cdot \mathbf{r} | \alpha \rangle \right|^2}$$

Matrix element dependent on spatial overlap of states
The scattering is dominated by *local* states

Under these assumptions, the core loss EELS spectrum probes the

- local density of states around the excited atom...
- with symmetry $l \pm 1 \dots$
- above the Fermi-level

The site and symmetry selected DOS

$$\frac{d^2\sigma(\Delta\mathbf{k}, E)}{d\Omega dE} = \frac{4}{a_0^2 \Delta k^4} \rho(E) |\langle \beta | e^{-i\Delta\mathbf{k}\cdot\mathbf{r}} | \alpha \rangle|^2$$

Direct comparison with calculated density of states (DOS)

$$\frac{d^2\sigma(\Delta\mathbf{k}, E)}{d\Omega dE} = \frac{4}{a_0^2 \Delta k^4} \rho(E) |\langle\beta|e^{-i\Delta\mathbf{k}\cdot\mathbf{r}}|\alpha\rangle|^2$$

- The transition matrix determines the underlying edge shape
- Usually slowly varying with energy
- The density of states gives more rapid variations on top of this
- Allows comparison with calculated DOS, e.g. from density functional theory (DFT)

Next time

- More on comparisons of EELS spectra with DOS
- Elemental quantification with EELS